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TRANSMITTAL FORM

(to be used for all correspondence after initial filing)

Application Number	10/033,323	
Filing Date	12/28/2001	
First Named Inventor	Rueckes, et al.	
Group Art Unit	2818	
Examiner Name	Not Yet Assigned	
Attorney Docket Number	112020.127/NAN-4	

Total Number of	n rages in This Subin	1331011	Attorney Docke	ot Humber		
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Amendment / Reply	,	Licensin	g-related Papers		Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)	
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SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT						
Firm or Individual name	Peter M. Dichiara, Reg. No. 38,005					
Signature	Signature Para Maria Co					
Dat	07/03/2003					
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Rueckes, Thomas et al.

Serial No.:

10/033,323

Examiner:

Unassigned

Filed:

December 28, 2001

Group Art Unit: 2818

For:

ELECTROMECHANICAL THREE-TRACE JUNCTION DEVICES

Attorney Docket No. 112020.127 / NAN-4

CERTIFICATE OF MAILING UNDER 37 C.F.R. 1.8(a)

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July 3, 2003

Tina M. Dougal

Date

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Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §§ 1.56 and 1.97-98, Applicants bring to the attention of the Examiner the following publications listed on the attached Form PTO-1449.

This submission does not represent that a search has been made or that no better art exists and does not constitute "prior art". Applicants reserve the right to take appropriate action to establish the patentability of the disclosed invention over the listed publications, should one or more of the publications be applied against the claims of the present application.

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Copies of the publications listed on the attached Form PTO-1449 are submitted herewith. It is respectfully requested that the Examiner initial and return a copy of the enclosed Form PTO-1449 with the next Patent Office communication.

It is Applicants' belief that that this Information Disclosure Statement is being filed prior to the mailing of the first Office Action on the merits and is therefore submitted as both timely and proper; thus, no fees are believed to be due. However, in the event of a fee deficiency, the Commissioner is authorized to charge any underpayment or credit any overpayment to Deposit Account No. <u>08-0219</u>.

Respectfully submitted,

Dated: July 3, 2003

Peter M. Dichiara Registration No. 38,005

Attorney for Applicants

Hale and Dorr LLP 60 State Street Boston, Massachusetts 02109

Tel: (617) 526-6466 Fax: (617) 526-5000

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Applicant
Thomas Rueckes et al.

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Group Art Unit

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EXAMINER INITIAL	DOCUMENT NUMBER	DATE	U.S. Patent Documents NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIAT
INITIAL	5,346,683	09/13/94	Green et al.	423	447.2	<u>IF AFFROFRIAT</u>
	5,424,054	06/13/95	Bethune et al.	423	447.2	
	5,456,986	10/10/95	Majetich et al.	428	403	
	5,482,601	01/09/96	Ohshima et al.	204	173	
	5,547,748	08/20/96	Ruoff et al.	428	323	
	5,626,812	05/06/97	Ebbesen et al.	264	248	
	5,716,708	02/10/98	Lagow	428	408	
	5,753,088	06/19/98	Olk	204	173	
	5,780,101	07/14/98	Nolan et al.	427	216	
	5,903,010	05/11/99	Flory et al.	257	24	
	5,925,465	07/20/99	Ebbesen et al.	428	408	
	5,928,450	07/27/99	Russell	156	169	
	5,946,930	09/07/99	Anthony	62	293	
	5,973,444	10/26/99	Xu et al.	313	309	Ħ
	5,985,446	11/16/99	Lagow	428	367	E
	5,993,697	11/30/99	Cohen et al.	252	502	ЭОТОННОЗ
	6,031,711	02/29/00	Tennent et al.	361	303	- B - E
	6,060,724	05/09/00	Flory et al.	257	24	
	6,063,243	05/16/00	Zettl et al.	204	164	ון די
	6,083,624	07/04/00	Hiura	428	408	2003 1TER
	6,105,381	08/22/00	Ghoshal	62	259.2	28
	6,136,160	10/24/00	Hrkut et al.	204	192.16	00
	6,146,227	11/14/00	Mancevski	445	24	
	6,156,256	12/05/00	Kennel	264	461	
	6,183,714 B1	02/06/00	Smalley et al.	423	447.3	
	6,203,814 B1	03/20/01	Fisher et al.	424	443	
	6,203,864 B1	03/20/01	Zhang et al.	427	592	
	6,221,330 B1	04/24/01	Moy et al.	423	447.3	
	6,231,744 B1	05/15/01	Ying et al.	205	324	
	6,231,980 B1	05/15/01	Cohen et al.	428	402	
	6,232,706 B1	05/15/01	Dai et al.	313	309	
	6,239,547 B1	05/29/01 .	Uemura et al.	313	495	

EXAMINER

DATE CONSIDERED

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Applicant

Thomas Rueckes et al.

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	5,196,396	03/23/93	Lieber	505	1	
	5,252,835	10/12/93	Lieber et al.	250	492.1	
	5,840,435	11/24/98	Lieber et al.	428	698	
	5,897,945	04/27/99	Lieber et al.	428	323	
	5,997,832	12/07/99	Lieber et al.	423	249	
	6,036,774	03/14/00	Lieber et al.	117	105	
	6,159,742	12/12/00	Lieber et al.	436	164	
	6,190,634 B1	02/20/01	Lieber et al.	423	439	
-	5,590,078	12/31/96	Chatter	365	189.01	
	5,799,209	08/25/98	Chatter	395	876	
	5,838,165	11/17/98	Chatter	326	38	
	6,108,725	08/22/00	Chatter	710	56	
	6,138,219	10/24/00	Soman et al.	711	149	
	6,212,597 B1	04/3/01	Conlin et al.	711	105	·
	6,237,130 B1	05/22/01	Soman et al.	716	10	EC
	4,853,893	08/01/89	Eaton, Jr. et al.	365	145	7
	4,888,630	12/19/89	Paterson	357	23.5	20 C C C C C C C C C C C C C C C C C C C
	5,198,994	03/30/93	Natori	365	145	ECHNDLOGY RECONDE
	5,444,421	08/22/95	Carroll et al.	331	111	€ 4 I
	5,479,172	12/26/95	Smith et al.	342	51	E /E D 4 2003 CENTER
	5,517,194	05/14/96	Carroll et al.	342	50	- R - C - C - C - C - C - C - C - C - C
	5,521,602	05/28/96	Carroll et al.	342	50	280
	5,533,061	07/02/96	Smith et al.	375	334	00
****	5,553,099	09/03/96	Carroll et al.	375	334	
	5,608,246	03/04/97	Yeager et al.	257	295	
	5,626,670	05/06/97	Varshney et al.	117	7	
	5,802,583	09/01/98	Yeager et al.	711	152	
	5,850,089	12/15/98	Varshney et al.	257	295	
	5,850,231	12/15/98	Orimoto et al.	345	507	
	5,909,624	06/01/99	Yeager et al.	438	396	
	6,025,618	02/15/00	Chen	257	295	
	6,044,008	03/28/00	Choi	365	145	
	6,128,214	10/03/00	Kuekes et al.	365	151	
	6,159,620	12/12/00	Heath et al.	428	615	

EXAMINER

DATE CONSIDERED

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INFORMATION DISCLOSURE IN AN APPLICATION

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2818

6,198,655 B1	03/06/01	Heath et al.	365	151	
5,198,390	03/30/93	MacDonald et al.	437	203	
5,316,979	05/31/94	MacDonald et al.	437	203	
5,426,070	06/20/95	Shaw et al.	437	203	
5,640,133	06/17/97	MacDonald et al.	333	197	
5,719,073	02/17/98	Shaw et al.	437	228	-
5,846,849	12/08/98	Shaw et al.	438	52	
5,847,454	12/08/98	Shaw et al.	257	734	
5,878,840	03/09/99	Tessum et al.	182	229	
5,914,553	06/22/99	Adams et al.	310	309	
5,939,785	08/17/99	Klonis et al.	257	729	
6,051,866	04/18/00	Shaw et al.	257	417	
6,259,277 B1	07/10/01	Tour et al.	326	136	
5,640,343	06/17/97	Gallagher et al.	365	171	
5,650,958	06/22/97	Gallagher et al.	365	173	
5,793,697	08/11/98	Scheuerlein	365	230.07	
5,841,692	11/24/98	Gallagher et al.	365	173	RECENE JUL 14 200 TECHNOLOGY CENTE
5,930,164	07/27/99	Zhu	365	158	NC -
5,946,228	08/31/99	Abraham et al.	365	173	
6,052,263	04/18/00	Gill	360	113	4 4
6,072,718	06/06/00	Abraham et al.	365	173	H + 13
6,104,633	08/15/00	Abraham et al.	365	171	节
6,166,948	12/26/00	Parkin et al.	365	173	2 2 2
6,219,212 B1	04/17/01	Gill et al.	360	324.2	800
4,701,842	10/20/87	Olnowich	364	200	0
4,985,871	01/15/91	Catlin	365	230.06	
5,161,218	11/03/92	Catlin	395	425	
5,184,320	02/02/93	Dye	365	49	
5,412,785	05/02/95	Skruhak et al.	395	375	
5,586,286	12/17/96	Santeler et al.	395	432	
5,608,888	03/04/97	Purcell et al.	395	412	
5,623,638	04/22/97	Andrade	395	494	
5,651,126	07/22/97	Bailey et al.	395	401	
5,652,856	07/29/97	Santeler et al.	395	432	

EXAMINER

DATE CONSIDERED

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Applicant

Thomas Rueckes et al.

Filing Date
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Group Art Unit 2818

5,699,317	12/16/97	Sartore et al.	365	230.06	_
5,271,862	02/24/98	Sartore et al.	395	445	
5,781,717	07/14/98	Wu et al.	395	182.06	<u> </u>
5,875,451	02/23/99	Joseph	711	105	
5,887,272	03/23/99	Sartore et al.	711	105	
6,038,637	03/14/00	Berube et al.	711	105	
6,049,856	04/11/00	Bolyn	711	168	
6,088,760	07/11/00	Walker et al.	711	104	
6,226,722 B1	05/01/01	Shippy et al.	711	168	
 6,233,665 B1	05/15/01	Bolyn	711	168	
5,444,651	08/22/95	Yamamoto et al.	365	108	
6,031,756	02/29/00	Gimzewski et al.	365	151	
3,448,302	06/03/69	Shanefield	307	318	
4,845,533	07/04/89	Pryor et al.	357	2	
4,876,667	10/24/89	Ross et al.	365	113	

			Foreign Patent Document	ts			
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS		LATION
INITIAL	NUMBER					YES	NO
	0 613 130 A1	08/31/94	EP			•	-
	0 665 187 A1	08/02/95	EP			LC.	7
	0 665 187 B1	12/29/97	EP	-		H.	
	0 989 579 A3	03/29/00	EP			ECHNOLOGY	عاداد
	0 945 402 A1	09/29/00	EP			45	-
	0 947 466 A1	10/06/99	EP			CE	£ [
	0 989 579 A3	03/29/00	EP			CENTER	200
	1 046 613 A2	10/25/00	ÉP			70	2693
	1 052 520 A1	11/15/00	EP			2800	
	1 054 249 A1	11/22/00	EP			0	
	1 059 266 A3	12/20/00	EP				
	1 061 040 A1	12/20/00	EP				
	1 061 043 A1	12/20/00	EP				
	1 061 044 A1	12/20/00	EP				
	1 061 544 A1	12/20/00	EP				
	1 061 555 A1	12/20/00	EP			***************************************	

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INFORMATION DISCLOSURE IN AN APPLICATION

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Applicant
Thomas Rueckes et al.

1 069 206 A2	01/17/01	EP			, .	
1 072 693 A1	01/31/01	EP				
1 100 106 A2	05/16/01	EP		†		
1 100 297 A2	05/16/01	EP				
WO 96/38410	12/05/96	PCT				_
WO 97/09272	03/13/97	PCT				
WO 97/43473	11/20/97	PCT				
WO 98/26871	06/25/198	PCT				
WO 98/39250	09/11/98	PCT .				
WO 98/48456	10/29/98	PCT		-		
WO 99/06618	02/11/99	PCT				
WO 99/47570	09/23/99	PCT		표		
WO 99/48810	09/30/99	PCT		TECHN		
WO 99/58748	11/18/99	PCT		2		72
WO 99/65821	12/23/99	PCT		10L0G		\overline{C}
WO 01/03208 -	01/11/01	PCT		0	ţ.	
WO 95/02709 -	01/26/95	PCT		22	2	
WO 95/02709 -	01/26/95	PCT		ER	2003	Ċ
WO 96/41043-	12/19/96	PCT		280		
WO 97/31139~	08/28/97	PCT		00		
WO 98/39251~	09/11/98	PCT				
WO 00/44094 -	07/27/00	PCT				
0 688 618 A2 ~	08/23/95	EP				
0 688 618 A3 ~	08/23/95	EP				
0 217 023 A2 -	04/08/87	EPO				
0 269 225 A2-	06/01/88	EPO				
0 269 225 A3	06/01/88	EPO				
0 269 716 A2_	12/28/88	EPO				
0 296 716 A3 ~	12/28/88	EPO				
0 315 392 A2 ~	05/10/89	EPO				
0 315 392 A3 _	05/10/89	EPO				

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A1	Winslow, Troy. "Advanced+ Boot Block World's First 0.18-Micron Flash Memory." Flash Products Group. April 17,

EXAMINER

DATE CONSIDERED

Subj. For, PTO-1449

INFORMATION DISCLOSURE IN AN APPLICATION

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Thomas Rueckes et al.

(Use several sheets if necessary)

Filing Date

Group Art Unit 2818

 Sheet
 6
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 21
 December 28, 2001

Π	2000.
	"Double Sided 4Mb SRAM Coupled Cap PBGA Card Assembly Guide." International Business Machines Corp. (IBM),
A2	1998.
АЗ	Tyagi et al. "A 130nm Generation Logic Technology Featuring 70nm Transistors, Dual Vt Transistors and 6 Layers of
^3	Cu Interconnects." Portland Technology Development.
A4	"Preliminary: 8Mb (256Kx36 & 512Kx18) and 4Mb (128Kx36 & 256Kx18) [IBM0418A8CBLBB, IBM0418A4CBLBB, IBM0436A8CBLBB, IBM0436A4CBLBB]." International Business Machines Corp. (IBM), 1998.
A5	Wei, Chengyu et al. "Temperature and Stain-Rate Dependent Plastic Deformation of Carbon Nanotube."
A6	"Package Mechanicals for USAR ICs." USAR Systems, Inc., 1998.
A7	Dipert, Brian. "Exotic Memories, Diverse Approaches." EDN Magazine. April 26, 2001, 56-70.
A8	Duan, Xiangfeng. "Indium Phosphide Nanowires as Building Blocks for Nanoscale Electronic and Optoelectronic Devices." Nature (2001); 409: 66-69.
A9	Yang. "A High Performance 180 nm Generation Logic Technology." Portland Technology Development.
A10	Dai, Hongjie. "Controlled Chemical Routes to Nanotube Architectures, Physics, and Devices." The Journal of Physical Chemistry B (1999); 103: 11246-11255.
A12	Callaby, D. Roy et al. "Solid State Memory Study Final Report." National Media Lab, Feb. 1994.
A13	Cui, Yi. "Doping and Electrical Transport in Silicon Nanowires." The Journal of Physical Chemistry B (2960); Vol. 104, No. 22: 5213-5216.
A14	Li, Mingtao et al. "Direct Three-dimensional Patterning Using Nanoimprint Lithography." Applied Physics Letters (2000); Vol. 78, No. 21: 3322-3324.
A15	IBM436A86SQKA)." International Business Machines Corp. (IBM), 1999.
A16	Dipert, Brian. "Memory Cards: Designing with a Full Deck." EDN Magazine. May 25, 2000.
A17	Schönenberger, Christian et al. "Physics of Multiwall Carbon Nanotubes." Physics World. April 4, 2000.
A18	Whatmore, Roger W. "Nanotechnology." Ingenia. February, 2000.
A19	"Nanochip NC800SX, 0.8 Gbyte Molecular Memory IC (R/W), Nanochip NC200SX, 0.2 Gbyte Molecular Memory IC (R/W), Nanochip NCM4510SX, Molecular Array Read/write Engine, Low Voltage Thermal Actuated, Dynamic Media Series M2, Nanochip NC4525DX, A/D-D/A Interface, Preliminary Specifications, Advance Information, (b) 1996-2000 Nanochip Document NCM2230500."
A20	Odom, Teri Wang et al. "Atomic Structure and Electronic Properties of Single-Walled Carbon Nanotubes." Nature (1998); 391: 62-64.
A21	Ouyang, Min. "Atomically Resolved Single-Walled Carbon Nanotube Intramolecular Junctions." Science (2001); 291: 97-100.
A22	Odom, Teri Wang et al. "Magnetic Clusters on Single-Walled Carbon Nanotubes: The Kondo Effect in a One- Dimensional Host." Science (2000); 290: 1549-1552.
A23	Wong, Eric et al. "Nanobeam Mechanics: Elasticity, Strength, and Toughness of Nanorods and Nanotubes." Science (1997); 277: 1971-1975.
A24	Hu, Jiangtao et al. "Controlled Growth and Electrical Properties of Heterojunctions of Carbon Nanotubes and Silicon Nanowires." Nature (1999); 399: 48-51.
A25	Rueckes, Thomas et al. "Carbon Nanotube-Based Nonvolatile Random Access Memory for Molecular Computing." Science (2000); 289: 94-7.
A26	Kim, Philip et al. "Nanotube Nanotweezers." Science (1999); 286: 2148-2150.
A27	Huang, Yu et al. "Directed Assembly of One-Dimensional Nanostructures into Functional Networks." Science (2001); 291: 630-33.
A28	Cui, Yi et al. "Functional Nanoscale Electronic Devices Assembled Using Silicon Nanowire Building Blocks." Science (2001); 291: 851-53.
A29	Oullette, Jennifer. "Exploiting Molecular Self-Assembly." The Industrial Physicist. American Institute of Physics, December 2000.
A30	Peng, Shu et al. "Chemical Control of Nanotube Electronics." Nanotechnology (2000); 11: 57-60.
A31	"The Ultimate Memory Guide." Kingston Technology (1998).
A32	Morales, Alfredo et al. "A Laser Ablation Method for the Synthesis of Crystalline Semiconductor Nanowires." Science (1998); 279: 208-11.

EXAMINER	DATE CONSIDERED				
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP § 609: Draw Line through citation if not conformance and not considered. Include copy with next communication to applicant.					

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Group Art Unit

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U.S. Patent Documents							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATI	E_
	4,324,814	4/13/82	Reichert	427	86		
	4,378,629	4/5/83	Bozlev et al.	29	580		
	4,495,511	1/22/85	Yoder	357	22		
	4,510,016	4/9/85	Chi et al	156	643		
	4,673,474	06/16/87	Ogawa	204	157.64		
	4,707,197	11/17/87	Hensel et al.	437	189		
	4,758,534	7/19/88	Derkits Jr. et al.	437	89		
	4,901,121	2/13/90	Gibson et al.	357	15		
	4,903,090	2/20/90	Yokoyama	357	22	E	
	4,939,556	07/03/90	Eguchi et al.	357	4	0	
	5,010,037	4/23/91	Lin et al.	437	200		U
	5,032,538	7/16/91	Bozler et al.	437	83	0G	一
	5,057,883	10/15/91	Noda	357	22		Ŧ
	5,089,545	02/18/92	Pol	524	17	<u> </u>	\leq
	5,155,561	10/13/92	Bozler et al.	357	22	2003 NITER	7
	5,168,070	12/1/92	Luth	437	31	1 28	
	5,175,597	12/29/92	Cachier et al.	257	267	00	

	Foreign Patent Documents						
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANS	LATION
INITIAL	NUMBER					YES	NO
	WO 98/42620 -	10/01/98	WIPO				
	WO 00/09443-	02/24/00	WIPO				
	WO 00/17101~	03/20/00	WIPO				
	WO 00/19494	04/06/00	WIPO				

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A1	Franklin, Nathan R. and Hongjie Dai, "An Enhanced CVD Approach to Extensive Nanotube Networks with Directionality." Advanced Materials (2000): 890 – 894.
A2	Kong, Jing; Chongwu Zhou; Erhan Yenilmez; Hongjie Dai. "Alkaline metal-doped n-type semiconducting nanotubes as quantum dots." ApplieDPhysics Letters (11 Dec. 2000): 3977 – 3979.
АЗ	Tombler, Thomas W.; Chongwu Zhou; Jing Kong; Hongjie Dai. "Gating individual nanotubes and crossed with scanning probes." <i>Applied Physics Letters</i> (24 April 2000): 2412 – 2414.
A4	Zhou, Chongwu: et al. "Electrical measurements of individual semiconducting single-walled carbon nanotubes of various diameters." Applied Physics Letters (20 March 2000): 1597 – 1599.

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DATE CONSIDERED

Subt. For, PTO-1449
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INFORMATION DISCLOSURE IN AN APPLICATION

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Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant

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U.S. Patent Documents								
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING IF APPR		
	5,290,715	3/1/94	Pardya	437	29			
	5,453,970	09/26/95	Rust et al.	396	176			
	5,475,341	12/12/95	Reed	327	566			
	5,563,424	10/8/96	Yang et al	257	40			
	5,589,692	12/31/96	Reed	257	23		-	
	5,739,057	04/14/98	Tiwari et al.	438	172	EC		
	5,747,180	05/05/98	Miller et al:	428	601	¥		-7-
	5,751,156	05/12/98	Muller et al.	324	699	010	\exists	쥬
	5,847,565	12/08/98	Narayanan	324	322	ΥΩ		\Box
	5,858,862	01/12/99	Westwater et al.	438	503	CE	ŧ	
	6,038,060	03/14/00	Crowley	359	328	Z	20	П
	6,069,380	05/30/00	Chou et al.	257	315	ER	ಪ	7
	6,495,258 B1	12/17/02	Chen et al	428	408	28		
	6,445,006 B1	09/03/02	Brandes et al	257	76	8		
	6,144,481	11/07/00	Kowarz, et al	359	291			

	Foreign Patent Documents						
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANS	LATION
INITIAL	NUMBER					YES	NO
	WO 00/48195 -	8/17/00	WIPO				
	JP 11-011917 -	01/19/99	Japan				_

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A5	Zhang, Y. and Hongjie Dai. "Formation of metal nanowires on suspended single-walled carbon nanotubes." Applied Physics Letters (6 Nov. 2000): 3015 – 3017.
A6	Chen, Robert J. et al. "Molecular photodesorption from single-walled carbon nanotubes." Applied Physics Letters (1 Oct. 2001): 2258 – 2260.
A7	Zhang, Y.et al. "Electric-field-directed growth of aligned single-walled carbon nanotubes." Applied Physics Letters (5 Nov. 2001): 3155 – 3157.
A8	Zhang, Y. et al. "Metal coating on suspended carbon nanotubes and its implication to metal-tube interaction." Chemical Physics Letters (24 Nov. 2000): 35 – 41.
A9	Chen, Robert J. et al. "Noncovalent Sidewall Functionalization of Single-Walled Carbon Nanotubes for Protein Immobilization." American Chemical Society (2001): 3838 – 3839.
A10	Li, Yiming et al. "Growth of Single-Walled Carbon Nanotubes from Discrete Catalytic Nanoparticles of Various Sizes." American Chemical Society (2001).
A11	Cassell, Alan M. et al. "Large Scale CVD Synthesis of Single-Walled Carbon Nanotubes." American Chemical Society (1999): 6484 – 6492.
A12	Fan, Shoushan et al. "Carbon nanotube arrays on silicon substrates and their possible application." Physica E

•	
EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered subother	or not ditation is in conformance with MPER & 600: Draw Line through

citation if not conformance and not considered. Include copy with next communication to applicant.

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Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant

Thomas Rueckes et al.

Filing Date

Group Art Unit

December 28, 2001

2818

		(2000): 179 – 183.
	 	Liu, Lei et al. "Controllable Reversibility of an sp2 to sp3 Transition of a single Wall Nanotube under the
	A13	Manipulation of an AFM Tip." Physical Review Letters (22 May 2000): 4950 – 4953.
	A14	Kong, Jing et al. "Quantum Interference and Ballistic Transmission in Nanotube Electron Waveguides." Physical Review Letters (3 Sept. 2001); 87, 106801(4).
	A15	Liu, C. et al. "Synthesis of Macroscopically Long Ropes of Well-Aligned Single-Walled Carbon Nanotubes." Advanced Materials (16 Aug. 2000); 12, 1190 – 1192.
	A16	Kiang, Ching-Hwa. "Growth of Large-Diameter Single-Walled Carbon Nanotubes." American Chemical Society (2000); 104, 2454 – 2456.
	A17	Cheung. Chin Li et al. "Growth and fabrication with single-walled carbon nanotube probe microscopy tips." Applied Physics Letters (2000); 76, 3136 – 3138.
	A18	Bozovic, Dolores <i>et al.</i> "Electronic properties of mechanically induced kinds on single-walled carbon nanotubes." Applied Physics Letters (4 June 2001); 78, 3693 – 3695.
	A19	Hafner, Jason H. et al. "High-Yield Assembly of Individual Single-Walled Carbon Nanotube Tips for Scanning Prone Microscopies." The Journal of Physical Chemistry (1 Feb. 2001); 105, 743 – 746.
	A20	Hafner, J.H. et al. "Structural and functional imaging with carbon nanotube AFM probes." Progress in Biophysics & Molecular Biology (2001); 77, 73 – 110.
	A21	Jorio, A. et al. "Joint density of electronic states for one isolated single-wall carbon nanotube studies by resonant Raman scattering." Physical Review B (2001); 63: 24541(4).
	A22	Filho, A. G. Souza et al. "Electronic transition energy Eli for an isolated (n, m) single-wall carbon nariotube obtained by anti-Stokes/Stokes resonant Raman intensity ratio." Physical Review (2002); 63, 2414@(4)
	A23	Saito, R. et al. "Chirality-dependent G-band Raman intensity of carbon nanotubes." Physical Review (2001); 64, 1 085312(7).
	A24	Jorio, A. et al. "Structural (n, m) Determination of Isolated Single-Wall Carbon Nanotubes by Resonant Raman Scattering." Physical Review Letters (5 Feb. 2001); 86, 1118 – 1121.
	A25	Woolley, Adam T. et al. "Structural biology with carbon nanotube AFM probes." Chemistry & Biology (2000); 7, TR R193 – 204.
	A26	Li, Yan et al. "Preparation of Monodispersed Fe-Mo Nanoparticles as the Catalyst for CVD Synthesis of Carbon Nanotubes." Chemical Material (2001): 13; 1008 – 1014.
	A27	Rao, C. N. R. et al. "Nanotubes." CHEMPHYCHEM (2001); 2, 78 – 105.
	A28	Nerushev, Oleg A. et al. "Carbon nanotube films obtained by thermal chemical vapor deposition." Journal of Chemistry Materials (2001); 11, 1122 – 1132.
	A29	Flahaut, E. et al. "Synthesis of single-walled carbon nanotube-Co-MgO composite powders and extraction of the nanotubes." Journal of Chemical Materials (2000); 10, 249 –252.
	A30	Dresselhaus, Mildred S. and Phaedon Avouris. "Introduction to Carbon Materials Research." Topics Applied Physics (2001); 80, 1 – 9.
	A31	Dresselhaus, Mildred S. and Morinobu Endo. "Relation of Carbon Nanotubes to Other Carbon Materials." Topics in Applied Physics (2001); 80, 11 – 28.
	A32	Dai, Hongjie. "Nanotube Growth and Characterization." Topics in Applied Physics (2001); 80, 29 – 53.
	A33	Charlier, Jean-Chrisophe and Sumio Iijima. "Growth Mechanisms of Carbon Nanotubes." Topics in Applied Physics (2001); 80, 55 – 81.
	A34	Tenne, Richard and Alex K. Zettl. "Nanotubes from Inorganic Materials." <i>Topics in Applied Physics</i> (2001); 80, 81 – 112.
	A35	Louie, Steven G. "Electronic Properties, Junctions, and Defects of Carbon Nanotubes." Topics in Applied Physics (2001); 80, 113 – 145.
	A36	Yao, Zhen et al. "Electrical Transport Through Single-Wall Carbon Nanotubes." Topics in Applied Physics (2001); 80, 147 – 171.
	A37	Odom, Teri Wang et al. "Scanning Probe Microscopy Studies of Carbon Nanotubes." Topics in Applied Physics ((2001); 80, 173 – 211.
	A38	Saito, Riichiro and Hiromichi Kataura. "Optical Properties and Raman Spectroscopy of Carbon Nanotubes." Topics in Applied Physics (2001); 80, 213 – 247.
L	A39	Fink, Joerg H. and Philippe Lambin. "Electron Spectroscopy Studies of Carbon Nanotubes." Topics in Applied

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is consider	ered, whether or not citation is in conformanc, with MPEP 8 609: Draw Line through

citation if not conformance and not considered. Include copy with next communication to applicant.

Subt. For, PTO-1449 NFORMATION DISCLOSURE IN AN APPLICATION (Use several sheets if necessary) 10

Docket Number 112020.127 NAN-4 **Application Number** 10/033,323

Applicant Thomas Rueckes et al.

Filing Date

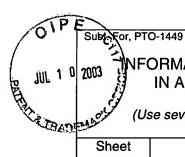
Group Art Unit

December 28, 2001 2818

	Physics (2001); 80, 247 – 272.
A40	Hone, James. "Phonons and Thermal Properties of Carbon Nanotubes." Topics of Applied Physics (2001); 80,
A41	273 – 286. Yakobson, Boris I. And Phaedon Avouris. "Mechanical Properties of Carbon Nanotubes." Topics in Applied
741	Physics (2001); 80, 287 – 327.
A42	Forro, Laszlo and Christian Schoenenberger. "Physical Properties of Multi-wall Nanotubes." <i>Topics in Applied Physics</i> (2001); 80, 329 – 391.
A43	Ajayan, Pulickel M. and Otto Z. Zhou. "Applications of Carbon Nanotubes." Topics in Applied Physics (2001); 80 391 – 425.
A44	Kong, J. et al. "Synthesis, integration, and electrical properties of individual single-walled carbon nanotubes." Applied Physics A (1999); 69, 305 – 308.
A45	Dai, Hongjie et al. "Exploiting the properties of carbon nanotubes for nanolithography." Applied Physics Letters (14 Sept. 1998); 73, 1508 – 1510.
A46	Soh, Hyongsok T. et al. "Integrated nanotube circuits." Applied Physics Letters (2 Aug. 1999); 75, 627 – 629.
	Bozler, C.O., et al., "Fabrication and Microwave Performance of the Permeable Base Transistor," IEEE Tech. Did
A47	Int. Electron Devices Meeting (1979) 384.
A40	Cheng, H. M. et al. "Large-scale and low-cost synthesis of single-walled carbon nanotubes by the catalytic
A48	pyrolysis of hydrocarbons." Applied Physics Letters (22 June 1998); 72, 3282 – 3284.
A49	Shim, Moonsub et al. "Polymer Functionalization for Air-Stable n-Type Carbon Nanotube Field-Effect Transistors
	Journal of American Chemical Society (2001); 123, 11512 – 11513.
A50	Haddon, R. C. "C70 Thin Film Transistors." Journal of the American Chemical Society (1996); 118, 3041 - 3042
A51	Hafner, Jason H. et al. "Direct Growth of Single-Walled Carbon Nanotube Scanning Probe Microscopy Tips." Journal of the American Chemical Society (1999); 121, 9750 – 9751.
A52	Hafner, Jason H. et al. "Growth of nanotubes for probe microscopy tips." Scientific Correspondence (29 April 1999); 398, 761, 762.
450	Bekyarova, E. et al. "Oxidation and Porosity Evaluation of Budlike Single-Wall Carbon Nanohorn Aggregates."
A53	American Chemical Society (2002).
A54	Hafner, Jason H. et al. "Catalytic growth of single-wall carbon nanotubes from metal particles." Chamical Physic
A34	Letters (30 Oct. 1998); 296, 195 – 202.
A55	Cheng, H. M. et al. "Large-scale and low-cost synthesis of single-walled carbon nanotubes by the catalysty pyrolysis of hydrocarbons." Applied Physics Letters (22 June 1998); 72, 3282 – 3284.
A56	Li, Yan et al. "Preparation of Monodispersed Fe-Mo Nanoparticles as the Catalyst for CVD Synthesis of Carbon Nanotubes." Chemical Material (2001); 13, 1008 – 1014.
A57	Kiang, Ching-Hwa. "Growth of Large-Diameter Single-Walled Carbon Nanotubes." Journal of Physical Chemisti A. (2000); 104, 2454 – 2456.
A58	Nerushev, Oleg A. et al. "Carbon nanotube films obtained by thermal chemical vapour deposition." Journal of Material Chemistry (2001); 11, 1122 – 1132.
A59	Kong, J. et al. "Synthesis, integration, and electrical properties of individual single-walled carbon nanotubes." Applied Physics A (1999); 69, 305 – 308.
A60	Zhou, Chongwu et al. "Electrical measurements of individual semiconducting single-walled carbon nanotubes of
A61	various diameters." Applied Physics Letters (20 March 2000); 76, 1597 – 1599. Yu, et al., J. Phys. Chem. B, 105:6831-6837 (2001).
A62	Berber, S., <i>Phys. Cheft.</i> 8, 103.0831-0837 (2001).
	Bahr, Jeffrey L. and James. M. Tour. "Highly Functionalized Carbon Nanotubes Using in Situ Generated
A63	Diazonium Compounds." Chemical Materials (2001); 13, 3823 – 3824.
A64	Peigney, Alain et al. "A Study of the Formation of Single- and Double-Walled Carbon Nanotubes by a CVD Method." Journal of Physical Chemistry B (2001); 105, 9699 – 9710.
A65	Yao, B. D. and N. Wang. "Carbon Nanotube Arrays Prepared by MWCVD." Journal of Physical Chemistry (200-105, 11395 – 11398.
A66	Ago, Hiroki et al. "Gas-Phase Synthesis of Single-wall Carbon Nanotubes from Colloidal Solution of Metal Nanoparticles." Journal of Physical Chemistry B (1 Nov. 2001); 105, 10453 – 10456.
	INGIN PARTICLES. JOURNAL OF PRISCAL CHEMISTRY D (1 NOV. 2001); 103, 10455 ~ 10456.

21

EXAMINER	DATE CONSIDERED				
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP § 609: Draw Line through citation if not conformance and not considered. Include copy with next communication to applicant.					



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11

Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant

Thomas Rueckes et al.

Filing Date

Group Art Unit

December 28, 2001

2818

	Sizes." Journal of Physical Chemistry B (2001); 105, 11424 – 11431.
	Ng, Hou Tee et al. "Soft-Lithography-Mediated Chemical Vapor Deposition of Architectured Carbon Nanotube
A68	Networks on Elastomeric Polymer." American Chemical Society (2001).
	Donoko V. et al. "Carbon Nanetuba Inter and Intromologular Logic Cates." Nane Letter (Sept. 2001): 1, 453
A69	456.
A70	
A70	
A71	Molecular Complex." Nano Letters (2001); 0, A – E.
A72	Reynoso, J. 391PGA Drawings (3): Project No. 32639103. Kyocera America, Inc. (12 April 1994).
A73	Diehl, Michael R. et al. "Self-Assembled, Deterministic Carbon Nanotube Wiring Networks." Angew. Chemical International Edition (2002); 41, 353 – 356.
A74	
	Sideray S. N. et al. "Cobalt Nanopartials Formation in the Person of Humar Cross Linked Polyatyrone." Chemical
A75	Materials (1999); 11, 3210 – 3215.
A76	Acids." Inorganic Chemistry (1999); 38, 5198 – 5202.
A77	Cage of Ferritin." Inorganic Chemistry (2000); 39, 1828 – 1830.
A78	
A79	Cao, Anyuan et al. "Macroscopic Three-Dimensional Arrays of Fe Nanoparticles Supported in Aligned Carbon Nanotubes." The Journal of Physical Chemistry B (2001); 105, 11937 – 11940.
	Li, Shoutian et al. "Semiconductor Nanoparticles in Contact: Quenching of the Photoluminescence from Silicon
A80	7319 – 7322.
A81	13, 1767 – 1770.
A82	Wei, B. Q. et al. "Organized assembly of carbon nanotubes." Nature (4 April 2002); 416, 495 – 496. ₩
A83	7han V. P. at al. "Eroquanay dependent electrical transport in cortical paratubes." Physical Paviaw P(2001): 64
A84	7hu H W. et al. "Direct Synthesis of Long Single-Walled Carbon Nanotube Strands." Science (2 Mb) (2002): 2060
A85	
A86	Franklin Nothern D. at al. "Patterned grouth of single walled sorben panetubes on full 4 inch waters." Andiidd
A87	For Chaushon at al. "Salf Oriented Bagular Arrays of Carbon Money bear and Their Field Emission Proportion."
A88	Sohn lung long at al. "Detterned calcative grouth of carbon panetuhes and large field emission from vertically
A89	Postma, Henk W. C. et al. "Manipulation and Imaging of Individual Single-Walled Carbon Nanotubes with an
A90	Chan L et al. "Large On-Off Ratios and Negative Differential Resistance in a Molecular Electronic Device."
A91	Collier C.P. et al. "Flootronically Configurable Molecular Record Logic Gates." Science Vol. 285, 16, Jul. 1999, pp.
A92	
A93	
	1 , , , , , , , , , , , , , , , , , , ,

EXAMINER	DATE CONSIDERED

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Applicant
Thomas Rueckes et al.

Filing Date

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EXAMINER	DOCUMENT NUMBER	DATE	ent Documents	CLASS	SUBCLASS	FILING DATE		
INITIAL	DOGGZ.TT TTGINDZ.TT	5,112	177.117.2	02.00	00000000	IF APPROPRIAT		
•	3,740,494	06/19/73	Dunand et al.					
	4,524,431	06/18/85	Haken et al.					
	3,892,890	07/01/75	Watanabe et al.					
	4,694,427	09/15/87	Miyamoto et al.					
	4,819,212	04/04/89	Nakai et al.					
	4,853,893	08/01/89	Eaton, Jr. et al.					
	4,888,630	12/19/89	Paterson			EC		
	4,947,226	08/07/90	Huang et al.			JUL		
-	4,979,149	12/18/90	Popovic et al.					
	5,031,145	07/09/91	Lever			- X		
	5,051,956	09/24/91	Burns			CE:		
	5,198,994	03/30/93	Natori			Ž00		
	5,592,642	01/07/97	Thomas			2 22		

EXAMINER	DOCUMENT	DATE	Patent Docume	CLASS	SUBCLASS	TRANSL	ATION
INITIAL	NUMBER					YES	NO
	WO 00/08650	08/03/99	PCT				
	WO 00/09443	07/02/99	PCT				
	WO 00/63115	04/14/00	PCT				
	WO 00/73204	05/25/00	PCT				
	WO 01/03208	06/30/00	PCT				

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A1	Tans, Sander J., "Room-temperature transistor based on a single carbon nanotube," Nature, May 1998, Vol. 393, pages 49-52
A2	Dillon, Anne C., "A Simple and Complete Purification of Single-Walled Carbon Nanotube Materials," Advanced Materials, 1999, Vol. 11, pgs. 1354-1358
A3	Cleland, A.N., "Single-crystal aluminum nitride nanomechanical resonators," Applied Physics Letters, September 24, 2001, Vol. 79, pgs. 2070-2072
A4	Ramsperger, U., "Fabrication and lateral electronic transport measurements of gold nanowires," Applied Physics Letters, January 1, 2001, Vol. 78, pgs. 85-87
A5	Calleja, M., "Fabrication of gold nanowires on insulating substrates by field-induced mass transport," Applied Physics Letters, October 8, 2001, Volume 79, pgs. 2471-2473

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered, whether or not citat citation if not conformance and not considered. Include copy with	

Subt. For, PTO-1449

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Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant
Thomas Rueckes et al.

Filing Date

Group Art Unit

December 28, 2001

2818

EVALUATED	DOCUMENT		Patent Documents		L OUBOLAGO	FILING DATE
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
1	5,538,916	07/23/96	Kuroi et al.			
	5,592,643	01/07/97	Thomas		TEC	
	5,592,644	01/07/97	Thomas		NO.	, 72
	5,994,733	11/30/99	Nishioka et al.		10	E(
	6,064,107	05/16/00	Yeh et al.		λS	一
	6,048,740	04/11/00	Hsu et al.		CE	+ V
	6,052,313	04/18/00	Atsumi et al.		HTE	<u>-[</u>
	6,062,931	05/16/00	Chuang et al.		TR.	<u> </u>
	6,052,313	04/18/00	Atsumi et al.		280	
	6,044,008	03/28/00	Choi		0	

		Foreign	Patent Documen	ts			
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
INITIAL	NUMBER					YES	NO
	WO 01/18246	08/28/00	PCT				
	WO 01/23303	08/03/00	PCT				
	WO 02/19420	08/31/01	PCT				
	WO 02/37500	05/24/01	PCT		4		

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A6	Kluth, P., "Fabrication of epitaxial CoSi₂ nanowires," Applied Physics Letters, August 6, 2001, Vol. 79, pgs. 824-826
A7	Zhang, Y., "Formation of metal nanowires on suspended single-walled carbon nanotubes," Applied Physics Letters, November 6, 2000, Vol. 77, pgs. 3015-3017
A8	Berry, A.D., "Fabrication of GaAs and InAs wires in nanochannel gas," Applied Physics Letters, November 4, 1996, Vol. 69, pgs. 2846-2848
A9	Li, Jian-Long, "Spontaneous formation of ordered indium nanowire array on Si(001)," Applied Physics Letters, October 22, 2001, Volume 79, pgs. 2826-2828
A10	Jorritsma, J., "Fabrication of large arrays of metallic nanowires on V-grooved substrates," Applied Physics Letters, September 4, 1995, Volume 67, pgs. 1489-1491
A11	Sekiba, Daiichiro, "Fabrication of stable nanopatterns on metals," Applied Physics Letters, September 30, 2002, Vol. 81, pgs. 2632-2634
A12	Yin, A. J., "Fabrication of highly ordered metallic nanowire arrays by electrodeposition," Applied Physics Letters, August 31, 2001, Vol. 79, pgs. 1039-1041
A13	He, J. Z., "Dispersion, refinement, and manipulation of single silicon nanowires," Applied Physics Letters, March 11, 2002, Vol. 80, pgs. 1812-1814

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered, whether or not citaticitation if not conformance and not considered. Include copy with	

Subt. For, PTO-1449 Application Number **Docket Number** 10/033,323 112020.127 NAN-4 INFORMATION DISCLOSURE
IN AN APPLICATION Applicant JUL 1 0 2003 Thomas Rueckes et al. (Use several sheets if necessary) Filing Date Group Art Unit 14 21 OF December 28, 2001 2818

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,087,293	07/11/00	Carnahan et al.			
	6,128,214	10/03/00	Kuekes et al.			
	6,165,890	12/26/00	Kohl et al.		- E	
	6,177,703	01/23/01	Cunningham		유	
	6,203,864	03/20/01	Zhang et al.		10	<u>ر</u> 22
	6,232,706	05/15/01	Dai et al.		00	- 0
	6,256,767	07/03/01	Kuekes et al.		7	手 四

		Foreign	Patent Documents		E 22	ت	
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS		SLATION
INITIAL	NUMBER				0	YES	NO
	WO 02/38496	11/12/01	PCT				
	WO 02/42204	11/2/01	PCT				
	WO 02/48701	12/11/01	PCT				

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A14	Franklin, Nathan R., "Integration of suspended carbon nanotube arrays into electronic devices and electromechanical systems," Applied Physics Letters, July 29, 2002, Vol. 81, pgs. 913-915
A15	Homma, Yoshikazu, "Growth of suspended carbon nanotube networks on 100-nm-scale silicon pillars," Applied Physics Letters, September 16, 2002, Volume 81, pgs. 2261-2263
A16	Yenilmez, Erhan, "Wafer scale production of carbon nanotube scanning probe tips for atomic force microscopy," Applied Physics Letters, March 25, 2002, Volume 80, pgs. 2225-2227
A17	Sax, Harald, "Polysilicon Overfill Etch Back Using Wet Chemical Spin-process Technology," 7 pgs.
A18	Dinaro, Joanna, "Analysis of an Elementary Reaction Mechanism for Benzene Oxidation in Supercritical Water, Combustion Institute," 2000, Volume 28, pgs. 1529-1536
A19	Monthioux, M., "Sensitivity of single-wall carbon nanotubes to chemical processing: an electron microscopy investigation," Carbon, 2001, Vol. 39, pgs. 1251-1272
A20	Hou, P. X., "Multi-step purification of carbon nanotubes," 2002 Elsevier Science Ltd., March 8, 2001, Vol. 40, pgs. 81-85
A21	Avouris, P., "Carbon nanotube electronics," Carbon, 2002, Vol. 40, pgs. 429-445
A22	Chen, Bin, "Heterogeneous Single-Walled Carbon Nanotube Catalyst Discovery and Optimization," Chemical Materials, December 7, 2001, Vol. 14, pgs. 1891-1896

EXAMINER	DATE CONSIDERED				
E70 (WIIITETT	DATE CONCIDENCE				
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP § 609: Draw Line through					
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INFORMATION DISCLOSURE IN AN APPLICATION (Use several sheets if necessary)					Applicant Thomas Rueckes et al.		
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		U.S.	Patent Documents			
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,262,469	07/17/01	Le et al.			
	6,300,205	10/09/01	Fulford et al.			
	6,314,019	11/06/01	Kuekes, et al.			
	6,320,428	11/20/01	Atsumi et al.		11	
	6,322,713	11/27/01	Choi et al.		TECH	
	6,325,909	12/4/01	Li et al.		NO NO	ر N
	6,331,209	12/18/01	Jang et al.		00	TC
	6,346,413	02/12/02	Fodor et al.		7	EI
-	6,348,295	02/19/02	Griffith et al.			VF
	6,348,700	02/19/02	Ellenbogen et al.		-	100 E D
	6,350,488	02/26/02	Lee et al.		7 2	5
	6,358,756	03/19/02	Sandhu et al.		C	5
	6,361,861	03/26/02	Gao et al.			
	6,362,073	03/26/02	Kim			

		Foreign	Patent Documer	nts			
EXAMINER	3000				TRANS	RANSLATION	
INITIAL	NUMBER					YES	NO
	WO 02/48822	12/11/01	PCT				
	WO 02/054505	12/21/01	PCT				
	WO 02/059898	01/23/02	PCT				
	WO 02/060812	01/29/02	PCT				

	Other Documents (Including Author, Title, Date Pertinent Pgs., Etc.)
A23	Maurin, I., "Carbon Miscibility in the Boron Layers of the MgB₂ Superconductor," Chemical Materials, 2002, pgs. A-D
A24	Hyeon-Lee, Jingyu, "Aero-Sol-Gel Synthesis of Nanostructured Silica Powders," Chemical Materials, 1997, Vol. 9, pgs. 2400-2403
A25	McEuen, Paul L., "Single-Walled Carbon Nanotube Electronics, to be published in the inaugural issue of the IEEE Transactions on Nanotechnology (2002), 9 pgs.
A26	Dürkop, T., "Nanotubes are High Mobility Semiconductors," Department of Physics, University of Maryland, 4 pgs.
A27	Choi, Hee Cheul, "Spontaneous Reduction of Metal Ions on the Sidewalls of Carbon Nanotubes," J. Amer. Chem. Soc., May 7, 2002, pgs. A-B
A28	Zheng, Bo, "Efficient CVD Growth of Single-Walled Carbon Nanotubes on Surfaces Using Carbon

EXAMINER	DATE CONSIDERED			
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP § 609: Draw Line through citation if not conformance and not considered. Include copy with next communication to applicant.				

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Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant
Thomas Rueckes et al.

Filing Date

Group Art Unit

21

December 28, 2001

2818

Monoxide Precursor,"Nano Letters, 2002, pgs. A-D

		U.S.	Patent Document	ts		
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,380,434	04/30/02	Chiang			
	6,400,088	06/04/02	Livingston et al.			- -
	6,400,091	06/04/02	Deguchi et al.		1	
	6,406,776	06/18/02	D'Evelyn		EC1	
	6,417,606	07/09/02	Nakamoto et al.		CHNO	, 70
	6,420,726	07/16/02	Choi et al.		10	JE (
	6,421,271	07/16/02	Gogl et al.		Υ <u>ς</u>	<u> </u>
	6,422,450	07/23/02	Zhou et al.		CEI	
	6,423,583	07/23/02	Avouris et al.		1	
	6,426,134	07/30/02	Lavin et al.		7.	<u> </u>
	2001/0023123 A1	09/20/01	Kim		8	
	2001/0023986 A1	09/27/01	Mancevski			
	2002/0055010 A1	05/9/02	Gao et al.			
	2002/0061441 A1	05/23/02	Ogura et al.			
	2002/0068170 A1	06/06/02	Smalley et al.			
	2002/0081380 A1	06/27/02	Dillon et al.			

Foreign Patent Documents							
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANS	LATION
INITIAL	NUMBER					YES	NO
	WO 02/060813	01/30/02	PCT ·				
,	WO 97/22971	12/12/96	PCT				

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A29	Deng, S. Z., "Synthesis of silicon carbide nanowires in a catalyst-assisted process," Chemical Physics Letters, April 26, 2002, Vol. 356, pgs. 511-514
A30	Zhang, R. Q., "Silicon nanotubes: Why not?," Chemical Physics Letters, 2002, Vol. 364, pgs. 251-258
A31	Lei, Y., "Fabrication, characterization and Raman study of TiO₂ nanowire arrays prepared by anodic oxidative hydrolysis of TiCl₃," Chemical Physics Letters, 2001, Vol. 338, pgs. 231-236
A32	Zheng, M. J., "Fabrication and optical properties of large-scale uniform zinc oxide nanowire arrays by one- step electrochemical deposition technique," Chemical Physics Letters, 2002, Vol. 363, pgs. 123-128
A33	O'Connell, Michael J., "Reversible water-solubilization of single-walled carbon nanotubes by polymer wrapping," Chemical Physics Letters, 2001, Vol. 342, pgs. 265-271

EX	(AI	ΛII	VE	ER

DATE CONSIDERED

OIPE Subt. For, PTO-1449 SINFORMATION DISCLOSURE	Docket Number Application Number 112020.127 NAN-4 10/033,323
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Sheet 17 OF 21	December 28, 2001 2818

		U.S.	Patent Document	ts		
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	2002/0081787 A1	06/27/02	Kohl et al.			
	2002/0088938 A1	07/11/02	Colbert et al.			
	2002/0090331 A1	07/11/02	Smalley et al.			
	2002/0092983 A1	07/18/02	Colbert et al.			
	2002/0092984 A1	07/18/02	Colbert et al.			
	2002/0096634 A1	07/25/02	Colbert et al.		EC	
	2002/0098135 A1	07/25/02	Smalley et al.		*	, , , , , , , , , , , , , , , ,
	2002/0102193 A1	08/01/02	Smalley et al.		סרס	EM
	2002/0102194 A1	08/01/02	Smalley et al.		750	1-1-0F
-	2002/0102196 A1	08/01/02	Smalley et al.		CE	- F
	2002/0102353 A1	08/01/02	Mauthner et al.		2	E 20

		Foreig	n Patent Document	ts	280		
EXAMINER	DOCUMENT	JMENT DATE COUNTRY CLASS		SUBCLASS	TRANS	LATION	
INITIAL	NUMBER					YES	NO
	426,282 B1	08/30/90	EP				
•	441,409 A3	07/27/88	EP				
	441,409 B1	07/27/88	EP				
	758,028 A3	07/09/96	EP			·	

	Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)
A34	Huang, Houjin, "Purification and alignment of arc-synthesis single-walled carbon nanotube bundles," Chemical Physics Letters,2002, Vol. 356, pgs. 567-572
A35	Kong, Jing, "Chemical vapor deposition of methane for single-walled carbon nanotubes," Chemical Physics Letters, 1998, Vol. 292, pgs. 567-574
A36	Bergbreiter, David E., "Using Soluble Polymers To Recover Catalysts and Ligands," Chemical Reviews, March 5, 2002, pgs. A-AM
A37	Roucoux, Alain, "Reduced Transition Metal Colloids: A Novel Family of Reusable Catalysts?," Chemical Reviews, January 30, 2002, pgs. A-V
A38	Yoshida, Jun-ichi, "Tag Strategy for Separation and Recovery," Chemical Reviews, March 18, 2002, pgs. A-X
A39	De Vos, Dirk E., "Ordered Mesoporous and Microporous Molecular Sieves Functionalized with Transition Metal Complexes as Catalysts for Selective Organic Transformations," Chemical Reviews, January 31, 2002, pgs. A-Z

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered, whether or not citatic citation if not conformance and not considered. Include copy with	

OIPE	Subt. For, PTC)-1449 DRMATION	DISCLO		Docket Number 112020.127 NAN-4	Application Number 10/033,323	
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		Foreigr	n Patent Documei	nts			
EXAMINER	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS		LATION
INITIAL	NUMBER					YES	NO
	1,205,436 A1	11/05/01	EP				
	1,209,123 A2	09/06/96	EP				
	1,225,613 A1	10/12/00	EP				
	2,364,933 A	07/18/01	GB			<u>-</u>	
	1,132,920 A2	02/27/01	EP		3.	-	

	ŢĒ
	Other Documents (Including Author, Title, Date Fertinent Pages, Etc.)
A40	Connelly, Neil G., "Chemical Redox Agents for Organometallic Chemistry," Chemical Reviews, January 9, 1996, Vol. 96, pgs. 877-910
A41	Dequesnes, Marc, "Calculation of pull-in voltages for carbon-nanotube-based nanoelectromechanical switches," Nanotechnology, January 22, 2002, Vol. 13, pgs. 120-131
A42	Serp, Philippe, "Chemical Vapor Deposition Methods for the Controlled Preparation of Supported Catalytic Materials," Chemical Reviews, April 10, 2002, pgs. A-AR
A43	Diehl, Michael R., "Self-Assembled, Deterministic Carbon Nanotube Wiring Networks," Angew. Qhem. Int. Ed., 200 Vol. 41, pgs. 353-356
A44	Wind, S.J., "Localized and Directed Lateral Growth of Carbon Nanotubes from a Porous Templated IBM T.J. Watson Research Center, 17 pgs.
A45	Wind, S. J., "Fabrication and Electrical Characterization of Top Gate Single-Wall Carbon Nanotube Field-Effect Transistors," IBM T. J. Watson Research Center, 14 pgs.
A46	Harutyunyan, Avetik R., "CVD Synthesis of Single Wall Carbon Nanotubes under "Soft" Conditions," Nano Letters, February 25, 2002, pgs. A-F
A47	Massot, L., "Electrodeposition of carbon films from molten alkaline fluoride media," Electrochimica Acta, January 28, 2002, Vol. 47, pgs. 1949-1957
A48	Heinze, S., "Carbon Nanotubes as Schottky Barrier Transistors," Physical Review Letters, September 2, 2002, Volume 89, pgs. 106801-1 through 106801-4.
A49	Duan, Xiangfeng, "Indium phosphide nanowires as building blocks for nanoscale electronic and optoelectronic devices," Nature, January 4, 2001, Vol. 409, pgs. 66-69
A50	Chen, Robert J., "Noncovalent Sidewall Functionalization of Single-Walled Carbon Nanotubes for Protein Immobilization," J. Amer. Chem. Soc., 2001, Vol. 123, pgs. 3838- 3839
A51	Puntes, Victor F., "Synthesis of hcp-Co Nanodisks," J. Amer. Chem. Soc., 2002, Vol. 124, pgs. 12874-12880
A52	An, Lei, "Synthesis of Nearly Uniform Single-Walled Carbon Nanotubes Using Identical Metal-Containing Molecular Nanoclusters as Catalysts," j. Amer. Chem. Soc., 2002, Vol (?), total of 4 pgs.
A53	Cassell, Alan M., "Directed Growth of Free-Standing Single-Walled Carbon Nanotubes," American Chemical Society, June 21, 1999, Vol. 121, pgs. 7975-7976
A54	Bahr, Jeffrey L., "Functionalization of Carbon Nanotubes by Electrochemical Reduction of Aryl Diazonium Salts: A Bucky Paper Electrode," American Chemical Society, 2001, Vol. 123, pgs. 6536-6542
A55	Fruchart, O., "Vertical self-organization of epitaxial magnetic nanostructures," Journal of Magnetism and Magnetic Materials, 2002, Vol. 239, pgs. 224-227

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered, whether or not citat citation if not conformance and not considered. Include copy with	

JUL 1 0 2003 1 Application Number Docket Number 10/033,323 INFORMATION DISCLOSURE IN AN APPLICATION 112020.127 NAN-4 Applicant Thomas Rueckes et al. (Use several sheets if necessary) Group Art Unit Filing Date 19 2818 OF 21 December 28, 2001 Sheet

A56	Zhang, J., "Fabrication and photoluminescence of ordered GaN nanowire arrays," Journal of Chemical Physics, October 1, 2001, Volume 115, pgs. 5714-5717
A57	Dubois, S., "Fabrication and properties of arrays of superconducting nanowires," Journal of Materials Research March 1999, Vol. 14, pgs. 665-671
A58	Liu, Z.Q., "Synthesis of α-SiO₂ nanowires using Au nanoparticle catalysts of a silicon substrate," Journal of Materials Research, March 2001, Vol. 16, pgs. 683-686
A59	Lei, Y, "Fabrication, characterization, and photoluminescence properties of highly ordered TiO₂ nanowire arrays, J. Material Research, April 2001, Vol. 16, pgs. 1138-1144
A60	Li, Y., "Fabrication of Highly ordered ZnO nanowire arrays in anodic alumina membranes," J. Materials Research, November 2000, Vol. 15, p. 2305-2308
A61	Sellmyer, D.J., "Magnetism of Fe, Co and Ni nanowires in self-assembled arrays," J. of Physics: Condensed Matter, (2000) Vol. 13, pgs. R433-R460
A62	Blick, R.H., "Nanostructural silicon for studying fundamental aspects of nanomechanics," J. of Physics: Condensed Matter, (2002), pgs. R905-R945
A63	Ciraci, S., "Quantum effects in electrical and thermal transport through nanowires," J. of Physics: Condensed Matter, (2001), pgs. R537-R568
A64	Yu, Jae-Young, "Silicon Nanowires: Preparation, Device, Fabrication, and Transport Properteis," J. Phys. Chem. B 2000, Vol. 104, pgs. 11864-11870
A65	Yu, Zhonghua, "(n, m) Structural Assignments and Chirality Dependence in Single-Wall Carbon Nanotube Raman Scattering," J. Phys. Chem. B 2001, Vol. 105, pgs. 6831-6837
A66	Wang, Y.W., "Fabrication of Ordered Ferromagnetic-Nonmagnetic Alloy Nanowire Arrays and their Magnetic Property Dependence on Annealing Temperature," J. Phys. Chem. B 2002, Vol. 106, pgs. 2502-2507
A67	Murphy, Robert, "High-Yield, Nondestructive Purification and Quantification Method for Multiwalled Carbon Nanotubes," J. Phys. Chem. B 2002, Vol. 106, pgs. 3087-3091
A68	Li, C.P., "Silicon Nanowires Wrapped with Au Film," J. Phys. Chem. B 2002, Vol. 106, pgs. 6980-6984
A69	Steuerman, David W., "Interactions between Conjugated Polymers and Single-Walled Carbon Nanotubes," J. Phys. Chem. B 2002, Vol. 106, pgs. 3124-3130
A70	Li, Jun, "Novel Three-Dimensional Electrodes: Electrochemical Properties of Carbon Nanotube Ensembles," J. Phys. Chem. B 2002, pgs. A-G
A71	Cassell, Alan M., "Large Scale CVD Synthesis of Single-Walled Carbor Nanotubes," J. Phys. Chem. B 1999, Vol. 103, pgs. 6484-6492
A72	Dai, Hongju, "Controlled Chemical Routes to Nanotube Architectures, Physics, and Devices," J. Phys. Chem. B 1999, Vol. 103, pgs. 11246-11255
A73	Chiang, I.W., "Purification and Characterization of Single-Wall Carbon Nanotubes (SWNTs) Obtained from the Gas-Phase Decomposition of CO (HiPco Process)," J. Phys. Chem. B 2001, Vol. 105, pgs. 8297-8301
A74	Tulchinsky, D.A., "Fabrication and domain imaging of iron magnetic nanowire arrays," J. Vac. Sci. Technol., May/June 1998. A 16(3), pgs. 1817-1819
A75	Yun, Wan Soo, "Fabrication of metal nanowire using carbon nanotube as a mask," J. Vac. Sci. Technol., Jul/Aug 2000, A 18(4), pgs. 1329-1332
A76	Batra, Inder P., "Quantum transport through one-dimensional aluminum wires," J. Vac. Sci. Technol., May/June 2002, B 20(3), pgs. 812 817
A77	Legrand, B., "Silicon nanowires with sub 10 nm lateral dimensions: From atomic force microscope lithography based fabrication to electrical measurements," J. Vac. Sci. Technol., May/June 2002, B 20(3), PGS.862-870
A78	Tsutsumi, Toshiyuki, "Fabrication technology of ultrafine SiO₂ masks and Si nanowires using oxidation of vertical sidewalls of a poly-Si layer." J. Vac. Sci. Technol., Jan/Feb 1999, B 17(1), pgs. 77-81
A79	Namatsu, Hideo, "Fabrication of one-dimensional nanowire structures utilizing crystallographic orientation in silicon and their conductance characteristics," J. Vac. Sci. Technol., Sept/Oct 1997, B 15(5), pgs. 1688-1696
A80	Namatsu, Hideo, "Fabrication of thickness-controlled silicon nanowires and their characteristics," J. Vac. Sci. Technol., Nov/Dec 1995, B 13(6), pgs. 2166-2169

EXAMINER	DATE CONSIDERED	TECHH
EXAMINER: Initial if citation is considered, vicitation if not conformance and not considered.	whether or not citation is in conformance with MPEP § 609: Include copy with next communication to applicant.	Draw Line through
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Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant

Thomas Rueckes et al.

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	9	Duit	

Group Art Unit

21 December 28, 2001

2818

A81	Cassell, Alan M., "Combinatorial Optimization of Heterogeneous Catalysts Used in the Growth of Carbon Nanofubes," Langmuir 2001, Vol. 17, pgs. 260-264
A82	Lewenstein, Justin C. "High-Yield Selective Placement of Carbon Nanotubes on Pre-Patterned Electrodes, Nano Letters., 2002, Vol 2, No. 5, pgs. 443-446
A83	Martino, Anthony, "Catalyst Testing of Highly Dispersed Metal Nanoparticles for Coal Liquefaction and Coal/Waste-Copressing," Catalysis and Chemical Technologies Department, Sandia National Laboratories, pgs:1-7
A84	Peng, X.S., "Electrochemical fabrication of ordered Ag ₂ S nanowire arrays," Materials Research Bulletin, 2002, No. 37, pgs. 1369-1375
A85	Robinson, L.A. W., "Self-aligned electrodes for suspended carbon nanotube structures," Microelectronics Research Centre, Cavendish Laboratory, University of Cambridge and Hitachi Cambridge Laboratory, pgs. 1-20
A86	Moore, Gordon E., "Cramming more components into integrated circuits," Electronics, April 19, 1965, Vol. 38, No. 8(4), 4 pgs.
A87	Fan, Hongyou, "Multiphased assembly of nanoporous silica particles," Journal of Non-Crystalline Solids (2001) Vol. 285, pgs. 71-78
A88	Franklin, Nathan R., "Integration of suspended carbon nanotube arrays into electronic devices and electromechanical systems," Applied Physics Letters, July 29, 2002, Vol. 81, No. 5, 913-915
A89	Kong, Jing, "Synthesis of individual single-walled carbon nanotubes on patterned silicon wafers," Nature, October 29, 1998, Vol. 395, pgs. 878-881
A90	Duan, Xiangfeng, "Nonvolatile Memory and Programmable Logic from Molecule-Gated Nanowires," Nano Letters, 2002, pgs. A-D
A91	Fuhrer, M.S., "High-Mobility Nanotube Transistor Memory," Nano Letters, 2002, Vol. 2, No. 7, pgs. 755-759
A92	Radosavljević, M.," Nonvolatile Molecular Memory Elements Based on Ambipolar Nanotube Field Effect Transitors," Nano Letters, 2002, Vol. 2, pgs. 761-764.
A93	Derycke, V., "Catalyst-Free Growth of Ordered Single-Walled Carbon Nanotube Networks," Nano Letters, 2002, pgs. A-D
A94	Joselevich, Ernesto, "Vectorial Growth of Metallic and Semiconducting Single-Wall Carbon Nanotubes," Nano Letters, xxxx, Vol. 0, pgs. A-E
A95	Javey, Ali, "Carbon Nanotube Transistor Arrays for Multistage Complementary Logic and Ring Oscillators," Nano Letters, 2002, pgs. A-D
A96	Robertson, John, "Section 11. Non-Crystalline Carbon, Properties and Prospects for Non-Crystalline Carbons," Journal of Non-Crystalline Solids 299-302, 2002, pgs. 798-804
A97	Ci, Lijie, "Double Wall Carbon Nanotubes Promoted by Sulfur in a Floating Iron Catalyst CVD System," Chemical Physics Letters 359, June 13, 2002, pgs. 63-67
A98	Grornov, A., "Purification of Carbon Nanotubes," Caramel Workshop, January 23, 2002, pgs. 1-13
A99	Cui, Yi, "Functional Nanoscale Electronic Devices Assembled Using Silicon Nanowire Building Blocks," Science, February 2, 2001, Vol. 291, pgs. 851-853
A100	Wang, Suhua, "Thermal Oxidation of Cu₂S Nanowires: a Template Method for the Fabrication of Mesoscopic Cu _x O (x = 1,2) Wires, Phys. Chem. Chem. Phys., 2002, Vol. 4, pgs. 3425-3429
A101	Untiedt, C., "Fabrication and Characterization of Metallic Nanowires," Physical Review B, July 15, 1997, Vol. 56, No. 4, pgs. 2154-2160
A102	Marsen, Bjorn, "Fullerene-Structured Nanowires of Silicon," Physical Review B, October 15, 1999, Vol. 60, No. 16, pgs. 11593-11600
A103	Berber, Savas, "Unusually High Thermal Conductivity of Carbon Nanotubes," Physical Review Letters, May 15, 2000, Vol. 84, No. 20, pgs. 4613-4616
A104	Yao, Zhen, "High-Field Electrical Transport in a Single-Wall Carbon Nanotubes," Physical Review Letters, March 27, 2000, Vol. 84, No. 13, pgs. 2641-2944
A105	Zhang, Y.F., "Liquid Phase Synethesis of Carbon Nanotubes," Physica B 323, 2002, pgs. 293-295
A106	Dresselhaus, M.S., "Raman Spectroscopy on One Isolated Carbon Nanotube," Physica B 323, 2002, pgs. 15-20
A107	Heinze, S., "Carbon Nanotubes as Schottky Barrier Transistors," Physical Review Letters, September 2, 2002, Vol. 89, No. 10, 106801-1 – 106801-4

EXAMINER	DATE CONSIDERED
EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP § 609: Draw Line through	



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Sheet

INFORMATION DISCLOSURE IN AN APPLICATION

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21

21

Docket Number 112020.127 NAN-4 Application Number 10/033,323

Applicant

Thomas Rueckes et al.

Filing Date

Group Art Unit

December 28, 2001

2818

A108	Fu, Qiang, "Electrodeposition of Carbon Films from Various Organic Liquids," Surface & Coatings Technology 124, 2000,
A109	pgs. 196-200 Hernadi, K., "Reactivity of Different Kinds of Carbon During Oxidative Purification of Catalytically Prepared Carbon Nanotubes,", Solid State Ionics 141-142, 2001, pgs. 203-209
A110	Colomer, J. F., "Different Purification Methods of Carbon Nanotubes Produced by Catalytic Synthesis," Synthetic Metals 103, 1999, pgs. 2482-2483
A111	Dalton, A.B., "A Functional Conjugated Polymer to Process, Purify and Selectively Interact with Single Wall Carbon Nanotubes," Synthetic Metals 121, 2001, pgs. 1217-1218
A112	Tat, Kerk Wai, "Preparation and Characterization of Coball/Silica Core-Shell Magnetic Nanoparticles," Dept. Chem., National University of Singapore 2000/2001, pgs.1-5
A113	Shipley, Microposit® XP-90104A E-Beam Resist, Preliminary Product Information, pgs. 1-2,
A114	Smalley, R. E., Foreword (Publication unknown), January 2001
A115	Dresselhaus, Mildred S., Preface (Publication unknown) January 2001
A116	Advanced Semiconductor Engineering, Inc., Substrate Design 420L BGA 35*35, Dwg. No. K-I-0420, 2 pages
A117	Integrated Device Technology, Inc., DA Package Design, 9/25/97, 2 pages
A118	Integrated Device Technology, Inc. BG Package Outline, 2/18/94
A119	Pimenta, M.A., "Diameter dependence of the Raman D-band in isolated single-wall carbon nanotubes," Physical Review B, Vol. 64 pgs. 04140-1-04140-4
A120	Duan, Xiangfeng, "Nonvolatile Memory and Programmable Logic from Molecule-Gated Nanowires, Nano Letters, March 2002, pgs. 1-4
A121	Introduction and Historical Perspective, Chapter 1, pgs. 1-48
A122	Modern CMOS Technology, Chapter 2, pgs. 49-92
A123	Crystal Growth, Wafer Fabrication and Basic Properties of Silicon Wafers, Chapter 3, pgs. 93-149

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JUL 14 2003

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citation if not conformance and not considered. Include copy with next communication to applicant.